

SANYO	No.2543	2SK715
		N-Channel Junction Silicon FET

AM Tuner, RF Amp Applications

Applications

- . AM tuner RF amp, low-noise amp
- . HF low-noise amp

Features

- . Adoption of FBET process
- . Large $|Y_{fs}|$
- . Small c_{iss}
- . Very low noise figure

Absolute Maximum Ratings at Ta=25°C

			unit
Drain to Source Voltage	V_{DSS}	15	V
Gate to Drain Voltage	V_{GDS}	-15	V
Gate Current	I_G	10	mA
Drain Current	I_D	50	mA
Allowable Power Dissipation	P_D	300	mW
Junction Temperature	T_j	125	°C
Storage Temperature	T_{stg}	-55 to +125	°C

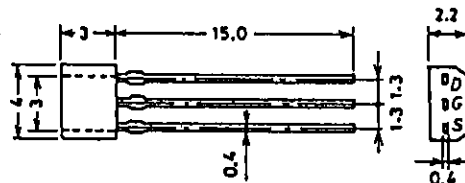
Electrical Characteristics at Ta=25°C

			min	typ	max	unit
Gate to Drain Breakdown Voltage	$V_{(BR)GDS}$	$I_G = -10\mu A, V_{DS} = 0$	-15			V
Gate Cutoff Current	I_{GSS}	$V_{GS} = -10V, V_{DS} = 0$			-1.0	nA
Cutoff Voltage	$V_{GS(OFF)}$	$V_{DS} = 5V, I_D = 100\mu A$		-0.6	-1.4	V
Drain Current	I_{DSS}	$V_{DS} = 5V, V_{GS} = 0$	5.0*		24.0*	mA
Forward Transfer Admittance	$ Y_{fs} $	$V_{DS} = 5V, V_{GS} = 0, f = 1kHz$	25	50		mS
Input Capacitance	c_{iss}	$V_{DS} = 5V, V_{GS} = 0, f = 1kHz$		10		pF
Reverse Transfer Capacitance	c_{rss}	$V_{DS} = 5V, V_{GS} = 0, f = 1kHz$		3.0		pF
Noise Figure	NF	$V_{DS} = 5V, R_g = 1k\Omega, I_D = 1mA, f = 1kHz$		1.5		dB

*: The 2SK715 is classified by I_{DSS} as follows: (unit: mA)

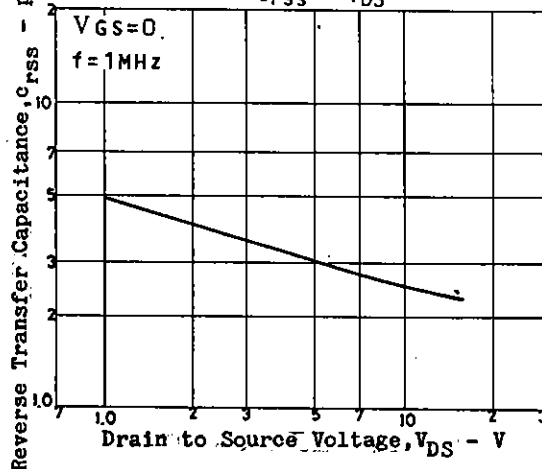
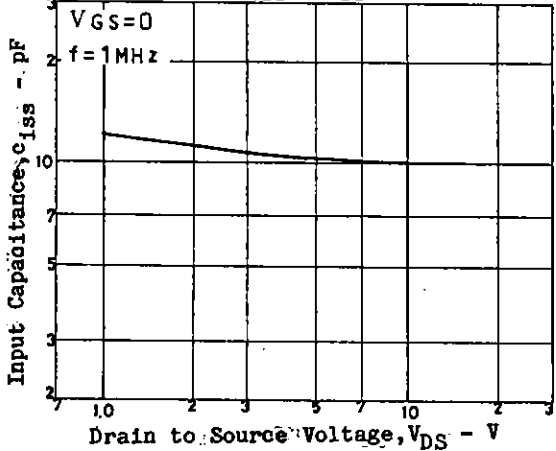
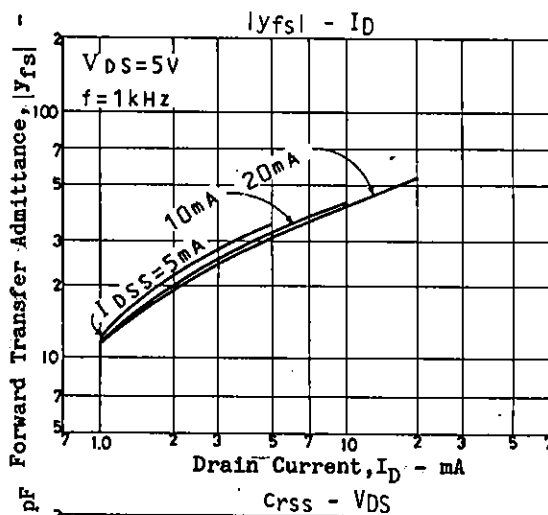
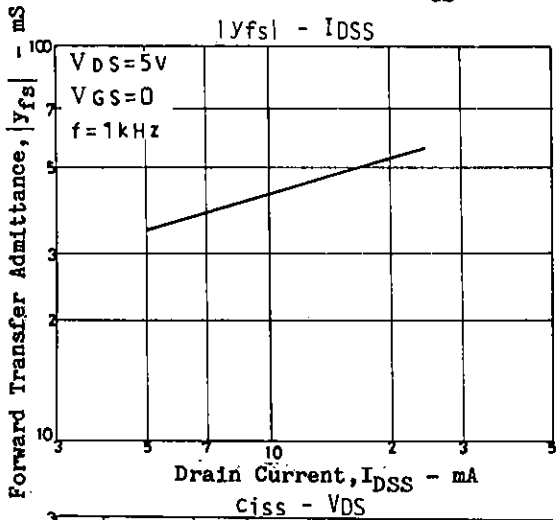
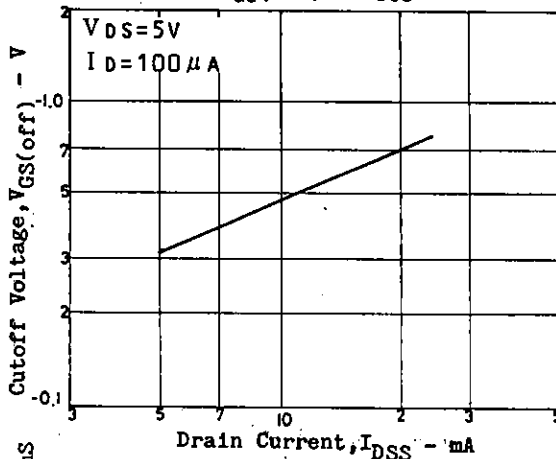
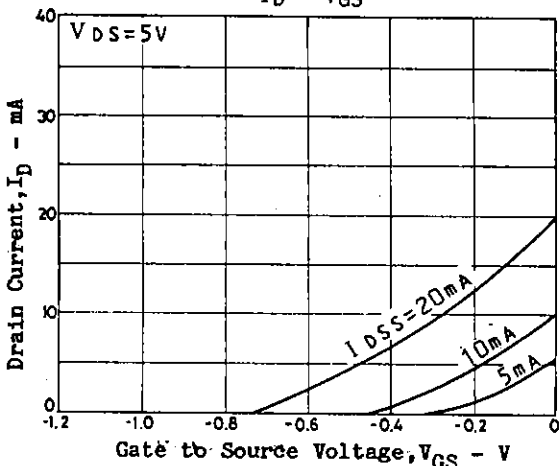
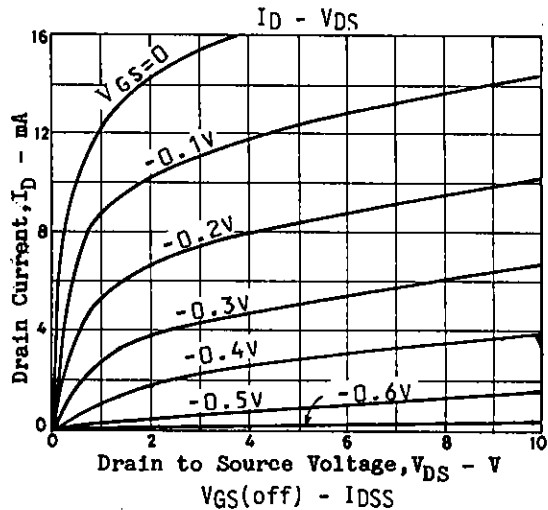
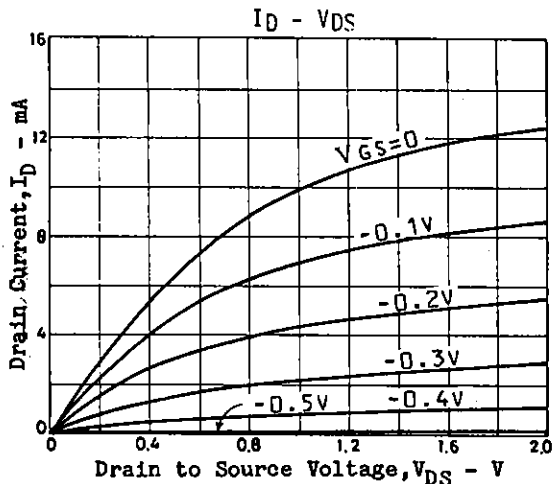
5.0	T	8.5	7.3	U	12.0	10.0	V	17.0	14.5	W	24.0
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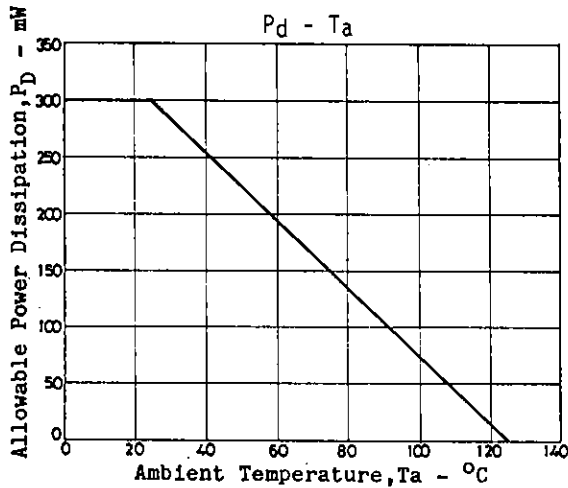
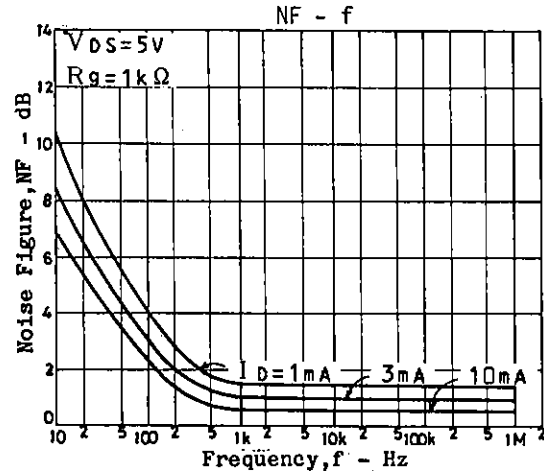
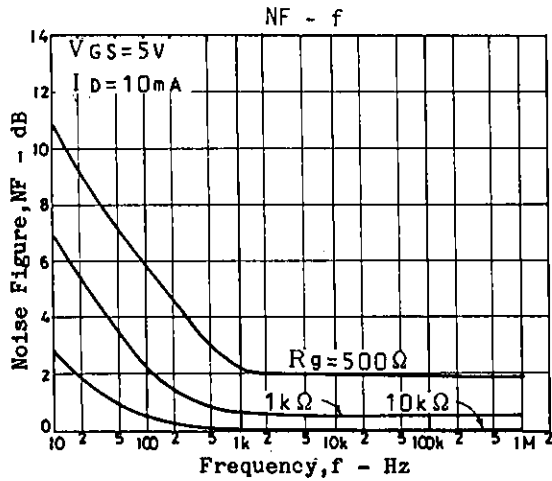
Package Dimensions 2034
(unit: mm)



D: Drain
G: Gate
S: Source

SANYO: SPA





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